



CST STUDIO SUITE

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Agenda

Introduction to CST Studio Suite

3D Experience Role: Electromagnetics Engineer

Applications of CST

Project Templates

High Frequency Design

Antenna & Microwave Device Examples

Multi-Physics Simulations

Low Frequency Design

Permanent Magnet Synchronous Motor Example

Q&A



Why Do I Need Electro-Magnetic Simulation ?

- 1. Do I really need a Simulation Software?
- 2. How will it help me in my Prototype Development?
- 3. Will it be cost effective to have such a Simulation Software ?
- 4. Can it really simulate what I need ?





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Example: Design & Test a Patch Antenna



Cost of Design & Test of a Prototype Patch Antenna?

- 1. First Design of Antenna. 3-4 Sample Designs: 1 week of design engineer time.
- 2. Send these samples for manufacturing: Turn around 1 week.
- 3. Test and Result Analysis of each sample. 1 week of 2-3 microwave engineer's time.
- 4. Total Cost ~ 10 20 K USD



Cost of Design & Test of a Prototype Patch Antenna?

Radiated Emissions Test Setup for Electromagnetic Compatibility (EMC)



S icro

Test Equipment for Antenna Testing

- Isolated Room with no EM feedbacks or interference.
- Network Analyzer
- Signal Analyzer
- Spectrum Analyzer
- High Bandwidth Oscilloscopes
- Microwave connectors, cables, probes etc.
- Total Cost ~ 100 K USD



Cost of Design & Test of a Prototype Patch Antenna?

- Second Round of Design based on first results. 1-2 week of Design Engineer's time.
- Second Batch of Test antennas to manufacture: 1 week
- Second Round of Testing: 1-2 weeks
- Final Design, manufacturing and testing 1-2 week.



Cost of Design & Test of a Prototype Patch Antenna?

- Biological Effect and Safety Tests: Probably outsource to specialized testing company.
- Must pass Government Safety Protocols and Test. If not then repeat the whole process !





A *capable* EM Simulation Software is much cheaper than trial/error product designdevelopment process !





CST Microwave Studio Workflow



CST Studio Suite | Key Features



- Electromagnetic (EM) field solvers for applications across the EM spectrum are contained within a single user interface
- Well known & proven solution among leading technology and engineering companies around the world
- Offers end-to-end solution for designing, analyzing, and optimizing electromagnetic components and systems
 Cadmicro

CST Studio Suite | Key Features

- Leading market solution for high frequency and low frequency electromagnetic simulation
- Optimize antenna and microwave devices
- Prevents and minimize electromagnetic interference (EMI) and electromagnetic compatibility (EMC) issues
- Coupled simulations: system-level, hybrid, multiphysics & EM/circuit co-simulation







Applications of CST Studio Suite



Energy, Process and Utilities



Power transformers



Insulators



Generators



High voltage components



Power transmission



Aerospace and Defense



Reflector antenna



Antenna feed



Interference analysis



Antenna arrays





EM immunity



Transportation & Mobility



Cabling EM behavior



Electric motors



On-board electronics





E-mobility, Wireless charging cadmicro

High Tech: Communication/IOT





Emissions and Interference



Flexible electronics





WiFi access point



Wearable devices



Life Sciences:



Imaging and diagnostics



Implant Safety



Highfield MRI



Heart Valve



Brain cancer detection



Pacemaker



Thermal cancer treatment



Hearing Aids



Large Vehicles (Buses, Trains, Planes, etc.)





Large Vehicles (Buses, Trains, Planes, etc.)

- Lightning Strike (Fast Transient EM Fields)
- High Voltage/Current
- Large Physical Size to Mesh
- Various Wavelengths (Wideband)



What is CST Studio Suite ?



SIMULIA Electromagnetics Product Portfolio





Antenna Magus An expert system for antenna design

Opera 2D and/or 3D low frequency simulation

Chip Interface

from 2D layout



Filter Designer 3D Simulation of passive microwave components



FEST 3D Design and analysis of filters and other waveguide components



IDEM Works Best-in-class tool for generation of broadband macromodels

Generation of complex 3D chip models



SPARK 3D

Multipactor and gas discharge breakdown analysis



System Simulator Design of electromechanical components

CST Studio Suite | Main Components

- 1. Microwave, RF & Optical (High Frequency)
- 2. EDA Electronics: PCB, Signal Integrity etc.
- 3. EMI-EMC: EM Interference
- 4. Particle Dynamics
- 5. Statics-Low Frequency:
 Generators/Motors. Permanent
 Magnets
- 6. Multi-Physics: Thermal and Structural





CST on Cloud | 3D Experience Platform

Electromagnetics Engineer | Connected Role

CST Studio Suite is installed (locally), licensed and launched from the platform (similar to 3DEXPERIENCE SOLIDWORKS)



Electromagnetics Engineer | Packaged with two roles



Package contains both roles to provide users a seamless experience

Apps included for both roles



CST Studio Suite: Main Functionality

- A. Modeling a Device
- **B.** Meshing the Models
- c. Choose a Solver: Time / Frequency
- **D.** HPC or Local Computing
- **E.** Example: Coaxial Connector



Creating a Model in CST Studio



CAD Import Handling



Electromagnetics Engineer | Workflow



Creating a Model in CST Studio

- A complete 3D Model can be created in CST Studio itself.
- It has a built-in Library of materials
- Includes non-homogenous and non-linear materials
- Electro-Magnetic, Thermal and Structural Properties can be defined for each (Multi-Physics)



Component Library

The Component Library offers a way to collect reusable components and to easily collaborate with other users sharing the same library path.

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Sep 14

- View all of the available components in the specified global libraries.
- Each component can be downloaded into the user's local directory for editing.
- CST Studio Suite includes pre-built models available for download in the library.



Curves

Curve Tools

Solids can be created from curves using the **Create Shape from Curve** options under the **Modeling** ribbon



- A. Extrude Curve: Extrusion of a planar curve
- B. Cover Curve: Creation of a sheet from a planar curve
- C. Sweep Curve: Sweep a 2D profile along a path
- D. Loft Curves: Lofting of two curves together



A

B

С

D













Curves

Analytical Curves

- 3D curves and faces can be created using analytical expressions.
- ▶ The Analytical Curve feature can be accessed from Curves under the Modeling ribbon.

Pick Points •		Create Analytical Curve		l.	
Curves Picks Pick Lists Picks Clear Picks Create 2D Curve ✓ Polygon ✓ Line ✓ Circle ✓ Circle ✓ Ellipse ✓ Arc ✓ Rectangle ✓ Spline Selected Edges Create 3D Curve ✓ 3D Polygon 3D Spline Analytical Curve ✓	P	Name: analytical1 Analytical definitions X(t) sin(t) Y(t) cos(t) Z(t) t/(2*pi) Parameter range Min(t): 0 Max(t): 10*pi	OK Cancel Preview Help		
Blend and Trim	1				


Curves

Analytical Face

- 3D curves and faces can be created using analytical expressions.
- ▶ The Analytical Face feature can be used from Faces under the Modeling ribbon for this.

	- L D	
b	Shape from Picked Faces	
1	Analytical Face	
0.0	Construction Faces	•
Ap	ertures (TLM mesh only)	



Name: OK face Cancel Analytical definitions Preview X(u,v) Preview u Help Y(u,v) Help Y(u,v) Y Z(u,v) S*cos(sqrt(u^2+v^2)) Parameter ranges Min(u): -10*pi Min(v): -10*pi Max(v): 10*pi Min(v): -10*pi Max(v): 10*pi Component: V component1 V	Create Analytical Fa	ce 🔼
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component1 v Material: Vacuum v	Parameter ranges Min(u): -10*pi Max(u): 10*pi Min(v): -10*pi Max(v): 10*pi Component: Component: Component: Component:	
Material: Vicuum ~	component1 ~	1
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	Vacuum ~	





Curves

Flex Tools

A. Wrap Curves: Wrap previously selected curves toward a shape. The wrap operation preserves the length of the curves.

B. Project Curves: Project previously selected curves toward a shape along the surface normal of the target shape. The projection operation does not preserve the curve length.



Materials in CST

roblem	type:	Defau	ilt		~		
eneral	Condu	uctivity	Dispersion	Thermal	Mechanics	Density	
Gene Mate	ral prop rial nam	erties ne:					
Ferri	te						
Mate	rial fold	er:					
			~				
Туре	E.						
Nor	mal		~		Nonlinear Pro	op	
Non	mal on:		~	Mu	Nonlinear Pro	р	
Non Epsil	mal on:			Mu 40	Nonlinear Pro	op	N.
Non Epsile	mal on:			Mu 40	Nonlinear Pro	pp)
Non Epsile	mal on:			Mu 40	Nonlinear Pro	pp	
Non Epsil 1	mal on: Conduct	tivity [Dispersion T	Mu 40	Nonlinear Pro	pp	
Non Epsil 1 Dectric	mal on: Conduct	tivity [Dispersion T	Mu 40	Nonlinear Pro	p))

- Define Electrical permittivity and Magnetic permeability
- Can be An-isotropic
- Thermal Conductivity, Specific Heat etc.

Material	Description			
PEC $(\sigma \rightarrow \infty)$	Perfect electric conductor			
	Recommended for the simulation of materials with a high but finite conductivity, e.g., copper, aluminum.			
Lossy metal (σ ≠ ∞)	Skin effect is taken into account. The skin depth must be much smaller than the material thickness i.e., fields cannot penetrate objects made of "lossy metal"			

Materials in CST

Anisotropic Material



Problem	type: Defa	ult		~			The ic	ons dep	ict whic
General	Conductivity	Dispersion	Thermal	Mechanics	Density		solver	conside	rs the
Gen	eral properties						given	material	proper
Fer	rite								
Mat	erial folder:						General Conc		nersion T
Typ	e.	~				C	Electric con	ductivity	
An	sotropic	~	Λ	AS LE	(MQS,F	=W)	E. condu	uctivity (x.y.z)	•
Eps	ilon (x,y,z):	$ \rightarrow $	Mu	(x y z):			1	1 1	S/m
1	1	1	40	0 400	400		Adva	nced Para	meters
			0					-	

Meshing in CST Studio

Volumetric & Surface Mesh Tetrahedral & Hexahedral Mesh





Meshing in CST

Adaptive Mesh Refinement

- Enabled by default.
- Automatic mesh refinement in CST Studio Suite tries to refine the initial mesh in a clever way such that the results are accurate.





Initial Mesh

Adapted Mesh

Meshing in CST

Curved Elements

- Improve the numerical representation of the structure.
- Supported by Tetrahedral and Surface meshes.





Meshing in CST

Smooth Mesh

Controls the ratio of the edge lengths between adjacent elements.





Various Solvers in CST Studio



CST Microwave Studio Solver Overview



CST Microwave Studio Solver Overview

Special Solvers



- Electrically very large structure
- Farfield and RCS calculation
- Nearfield/farfield source for antenna placement calculations



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- Eigenmode calculation
- Hexahedral/tetrahedral mesh
- External Q-factor calculation

- Electrically large structure
- Characteristic mode analysis (CMA)
- Scattering parameter matrices

- Planar multilayer structure
- Characteristic mode analysis (CMA)
- Method of Moment (MoM) based

Low Frequency-Static Solvers

- Static Solvers
 - Electrostatic, Stationary Current and Magnetostatic Solvers: Do not take time-dependent effects into account. Presume a stationary state: d/dt = 0.







Dynamic Solvers

Consider time dependency, either in the frequency domain (electroquasistatic, magnetoquasistatic and full wave) or in the time domain (electroquasistatic, magnetoquasistatic).







Multi-Physics Solvers

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Thermal Solvers	Conduction	Convection	Radiation	Mesh
Steady-State & Transient	Yes	Approximated using Thermal Surface Properties	Surface-to-Ambient only	Tetrahedra Hexahedra
Conjugate Heat Transfer (Steady-State & Transient)	Yes	Yes	Yes Surface-to-Surface	Octree- Hexahedra
Mechanical Solver	Elastic Deformation	Thermal Stress	Nonlinear Properties	Mesh
Structural Mechanics	Yes	Yes	Temperature-Dep. Young's Modulus	Tetrahedra only

Caumero

Time vs. Frequency Domain Solvers



Time Domain Solver



- The largest simulation flexibility is offered by the time domain solvers, which can obtain the entire broadband frequency behavior of the simulated device from a single calculation run.
- These solvers are remarkably efficient for many high frequency applications such as connectors, transmission lines, waveguide components, and antennas, amongst others.
- Two time domain solvers are available, both using a hexahedral mesh, either based on the Finite Integration Technique (FIT) or on the Transmission-Line Matrix (TLM) method. The latter is especially well suited to EMC/EMI/E3 applications

Time Domain Solver

Behind the Scenes

- 1. The model is excited with a broadband signal (Gaussian pulse).
- 2. The response of the model is monitored in the time domain (output time signals).
- 3. A discrete Fourier Transform is applied automatically to the time signals to obtain the broadband behavior of the model in the frequency domain (broadband S-parameters).



Time Domain Solver



- Ports sequentially processed (simultaneous excitation of a combination possible)
- Broadband
- Very efficient for high level of geometric complexity
- Slows down at low frequencies
- High Q structures require long simulation time
- Able to handle large model
- Great speedup with GPU



- Frequency samples processed sequentially, additional ports not time demanding (direct solver)
- Mesh generation can be difficult for highly complex geometries
- Works well below 1 MHz
- Can handle high Q structures
- Small to medium models
- Great speedup with multi-core CPU

Hexahedral and Tetrahedral Mesh

T





Memory and Time

- Time Domain solver
 - Memory efficient



- Scales linearly with no. of mesh cells
- Approx. estimate for CPU RAM 1GB per 4 million cells*
- Approx. estimate for GPU RAM 1GB per 10 million cells*
- Frequency Domain solver
 - Memory hungry for larger models
 - Iterative solver consumes less memory than direct solver
 - Memory requirement is solver order dependent (default is 2nd order)



Number of mesh cells

* These estimates depend on several factors including material type (lossy, dispersive dielectrics may consume more memory), boundary conditions, etc.

Selecting the Most Appropriate Solver



Selecting the Most Appropriate Solver





HPC & Cloud Computing





Supported Acceleration Methods by Solver

Solver	Multithreading	GPU Computing	Distributed Computing	MPI Computing
T	\checkmark	\checkmark	\checkmark	\checkmark
F	\checkmark		\checkmark	\checkmark
		\checkmark		\checkmark
A				
Pic	\checkmark	\checkmark	\checkmark	
WAK	\checkmark			\checkmark

Note: The F-Solver supports MPI with the DDM solver. Please refer to the MPI Computing Guide for supported solvers, features and limitations.

Multithreading Scalability

- The bottleneck which limits the performance of the Transient Solver is the memory bandwidth of the system (i.e. the Transient Solver algorithm is memory bound)
- Many CPU cores are competing for memory access.

Solution → Hardware Acceleration





GPU Computing — Typical Performance



GPU Computing — Typical Performance



Distributed Computing (1/2)

Overview

- Some parts of the simulation tasks are independent of each other:
 - Computation of different frequency samples for F-solver and I-solver
 - Simulations performed during a parameter sweep or optimization
 - Excitations from multiple sequential ports
- DC allows the distribution of independent simulation tasks, from a single project, on various systems within the same network.
- Hardware resources can be shared.



The DC functionality is part of each standard license, for up to two CPU devices/sockets.

Distributed Computing (2/2)

Working Principle

- 1. Users submit simulation jobs from their front end to the DC Main Controller
- 2. The DC Main Controller acts as a queuing system which selects solver servers based on the criteria entered in the solver setup.
- 3. The DC Main Controller then sends the simulation tasks over the network to the selected Solver Servers when they are available. Tasks are submitted on a "first come, first serve" basis.
- Once the job is complete on the Solver Server, the job is sent back to the Main Controller to queue for the final transfer back to the corresponding front end.











MPI Computing

- MPI computing splits the computational workload for a simulation among computational resources either in a shared memory or distributed memory environment.
- MPI differs from Distributed Computing in that it can assign computational tasks which are not independent of each other to computational resources, such that these resources work on the tasks in parallel (e.g., field computations in different areas of a 3D model).
- MPI Computing provides an option for solving very large models, which might otherwise not fit in the resources available on a single workstation or server.
- Some appropriate applications for use with MPI Computing:
 - Electrically very large structures (e.g., RCS or lightning strike simulation on aircraft)
 - Extremely complex structures (e.g., SI simulation for full package)





Example: Coax Connector



Example: Coax Connector

Perform an optimization to reduce reflections by parameterizing the offset parameter





Multi-Physics



What is CST Multi-Physics Studio?

- CST MPhysics Studio is a software package from the CST Studio Suite family which allows thermal and mechanical simulations.
- It is based on the ACIS modeling kernel.
- Full parameterization of the structure modeler enables the use of variables in the definition of your component. In combination with the built-in optimizer and parameter sweep tools, CST MPhysics Studio is capable of analyzing and designing thermal and mechanical aspects of devices.
- After the component has been modeled, a fully automatic meshing procedure is applied before a simulation engine is started.
- A key feature of CST MPhysics Studio is its tight integration with the other CST Studio products. This allows a workflow for coupled EM-Multiphysics simulations.

Stationary Thermal Solver THs

Key Features

- Steady-state solver
- Supports hexahedral and tetrahedral grids
- Uni- and bidirectional coupling with EM solvers
- Moving Media
- Bio-heat transfer

Typical Applications

- Heat distribution in PCB
- Induction heating
- Hyperthermia treatment







Transient Thermal Solver

Key Features

- Transient simulation with arbitrary time signals for sources
- Supports hexahedral and tetrahedral grids

THt

- Uni- and bidirectional coupling with EM solvers
- Moving Media
- Bio-heat transfer

Typical Applications

- Microwave heating
- Induction hardening
- Temperature-dependent materials







- When accurate convection and radiation calculations are needed, the Conjugate Heat Transfer (CHT) solver is more appropriate to use.
- The CHT solver uses the Computational Fluid Dynamics (CFD) technique to solve 3D mass, momentum and energy conservation equations, collectively known as the Navier-Stokes equations. Written in a general form:

$$\frac{\partial \rho \phi}{\partial t} + \nabla \cdot (\rho \boldsymbol{U} \phi) = \nabla \cdot (\Gamma_{\phi} \nabla \phi) + S_{\phi}$$

where ρ , t, U, Γ_{ϕ} , S_{ϕ} are fluid density, time, velocity vector, diffusion coefficient, source respectively, and ϕ is a general variable, representing velocity components, temperature, mass, etc.

The CHT solver employs octree-based hexahedral meshing, which can be very tolerant of geometric issues often accompanying complex CAD geometries.


Modeling Flow

- Natural Convection
 - Typical scenario: The object is sitting in a seemingly "still" environment
 - The environment is actually not very still: the background air is usually being heated by the object and becomes lighter. The buoyancy force drives hotter air upwards. This is called Natural Convection.
 - Thermal radiation also plays an important role in Natural Convection.



Modeling Flow

- Forced Convection
 - Very often a mechanical device (e.g., certain types of fans) is used to enhance the cooling by exerting forces on the background fluid. This is called Forced Convection.
 - To model Forced Convection, three mechanisms can be used
 - Flow boundary
 - Fan
 - Opening
 - Usually under Forced Convection, thermal radiation, although still present, plays a minor role in dissipating heat, and can often be ignored.





Moving Media

- When the material moves, the spot of heating moves relative to the material.
 - Usually a 'heating' trace can be seen from the solution
- A non-dimensionless number called the Peclet number, which is defined as

$$Pe = c\rho \frac{\mathbf{L} \cdot \mathbf{v}}{\lambda}$$

where

- c: specific heat (heat capacity),
- ρ : density
- λ : thermal conductivity
- v : velocity of moving media
- L : characteristic (cell) length

can be used as a guidance of mesh size.



The Peclet number usually needs to be <1; therefore, higher speeds require a finer mesh.









Coupled Simulations with Thermal or Mechanical Solvers: EM-Multiphysics couplings:

- Field monitor results from a high frequency transient, eigenmode or frequency domain solver can be used as heat sources for thermal simulations.
- Based on the thermal results a subsequent stress simulation can be performed, and the impact of the stress on the EM simulation can then be considered when performing a sensitivity analysis with the frequency domain or eigenmode solver with a tetrahedral mesh.
- Temperature fields calculated by the thermal solvers can be imported by the high frequency time and frequency domain solvers to simulate the effects of temperature dependent materials.

Low Frequency Simulation



CST EM Studio Solvers Overview

Static Solvers

Electrostatic, Stationary Current and Magnetostatic Solvers: Do not take time-dependent effects into account. Presume a stationary state: d/dt = 0.







Dynamic Solvers

Consider time dependency, either in the frequency domain (electroquasistatic, magnetoquasistatic and full wave) or in the time domain (electroquasistatic, magnetoquasistatic).







Due to different mathematical formulations, each solver class has its own sources.





- Magneto(quasi)static and Fullwave solvers:
 - Coils and coil segments
 - Current paths
 - Voltage paths (LF, LT)
 - Current density distribution from Js (Ms)
 - Permanent magnets (Ms, LT)
 - Homogeneous magnetic source fields







- Electro(quasi)static solvers:
 - Potentials
 - Field Grading Source
 - Charges

Source	Solver	Select?	Enter?
Electric potential	Es Js Ms LF LT	PEC Face	Potential Value (V)
Charge	Es	PEC Face	Charge Value (C)
Charge distribution	Es	Surface of "normal" Body	Total Charge (C) Charge Density (C/m ³)
Permanent magnet	Ms	Surface of Body	Remanent Magnetization+ Permeability, J(H)-Curve
Current port	Js Ms LF LT	Face	Current
Current path	Js Ms LF LT	Curve	Current / Phase
Voltage path	LF LT	Curve	Voltage / Phase



Coil	Ms LF LT	 Profile Curve or Face Path Curve 	Current/ Voltage, Phase, Number of Turns, Resistance	
Coil segment	Js Ms LF LT	 Profile Curve or Face Path Curve or Pick Point 	Current / Voltage, Phase, Number of Turns, Height (optional)	
Magnetic source field	Ms LF LT	i	Field Vector	
Stationary current field			Toggle on in Solver dialog box:	
	1015		Precompute stationary current field	



Ms

Magnetostatic Solver

- ► The main task for the solver is to calculate the flux density $B = \nabla \times A$ and the magnetic field strength $H = \mu^{-1}(B)B M_{PM}(B)$ with the magnetization $M_{PM}(B)$ of permanent magnets under static conditions. The primary solution quantity is the magnetic vector potential A.
- Flux linkage, force and torque can be calculated as well as inductance matrices.
- Planar meshes can be used for 2D simulations.
- Applications include transformers, permanent magnets, inductive sensors, coils, actuators and electric machines.





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Force and Torque Calculation

- After the field calculation, the forces/force density and torques on 3D objects such as solids, magnets and coils or on groups of 3D objects can be calculated as a postprocessing step.
- The algorithm implemented is discretely equivalent to the virtual work method.
- For time harmonic fields the force represents a quantity changing in time and will be characterized by three parameters in each vector component: the DC value F_{DC} and the complex AC amplitude F_{AC}

 $F(t) = F_{DC} + \operatorname{Re}(\operatorname{Re}(F_{AC}) + j \cdot \operatorname{Im}(F_{AC})e^{j\omega t})$

- The force computation method requires objects which are completely surrounded by the background or by objects that are equivalent to the background.
- An object is considered equivalent to the background if
 - it has the same material coefficients (e.g., for electrostatics the same permittivity, or for magnetostatics the same permeability);
 - it is not occupied by a source.





LF Time Domain Solver



- The LF Time Domain Solver can be used to solve electromagnetic field transient problems in the time domain.
- The main task for the solver is to calculate the time evolution of losses and energies.
- Applications include transformers, coils, proximity sensors, iron loss calculations, wireless power transfer, electric machines, linear and rotational motion.
- Two equation types can be solved with the LF Time Domain Solver:
 - Magnetoquasistatic (MQS)
 - Electroquasistatic (EQS)

solver settings	Ctart
Equation type:	Start
Magnetoquasistatic 🗸 🗸	Close
Magnetoquasistatic	Apoly
Liectroquasstatic	4441
i cu di icurai	Ontimizer
Accuracy:	Opunize
1e-6 ~	Par. Sweep
Chara can dt data in cadha	
	Acceleration
Simulation settings	Specials
Simulation duration:	Simplify Model
0	Co-simulation
Max. signal duration: 1	C
Source and signal list: Excitations	Help
Time integration settings Method:	
Low order \sim	

L3.26

LF Time Domain Solver

Define a Rotation

- Select Simulation: Motion > Motion > New Rotation.
- 2. In the dialog box that appears, set the properties.
- Select New gap from radius to define the rotor.
- Double-click the outer radius/polygon in working plane or press Esc to show the dialog box.



Name:	OK
gap 1	
Outer radius:	Cancel
4	Preview
Inner radiur:	Help

3	New Rotation	
Motion	New Translation	
Motion	tion	
Active		ОК
Basic settings		Cancel
Name:	Rotation1	Preview
Active gap:	[New gap from radius]	Help
Rotation axis	[New gap from polygon]	
Direction:	OU OV ®W	
U center:	0.0	
V center:	0.0	
W center:	0.0	
Movement		
 Constant 	⊖Signal based ⊖Equation	
Angular velocity (rpm):	1.0	

L3.32

Low Frequency Example

Permanent Magnet Synchronous Motor



Thank you!



Questions & Answers